



**DSM80100M** 

#### PNP TRANSISTOR WITH DUAL SERIES SWITCHING DIODE

#### Features

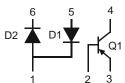
- Integrates one PNP Transistor (Q1) and two Switching Diodes (D1, D2) in a Single Compact Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **Mechanical Data**

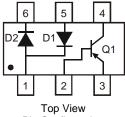
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe (Lead-Free Plating). Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.01 grams (Approximate)



Top View



**Device Schematic** 



Pin Configuration

#### Ordering Information (Note 4)

Part Number	Case	Packaging
DSM80100M-7	SOT26	3,000/Tape & Reel

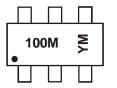
No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

Notes:

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



100M = Product Type Marking Code (See Electrical Characteristics Table) YM = Date Code Marking Y = Year (ex: B = 2014) M = Month (ex: 9 = September)

Date Code Key												
Year	201	4	2015		2016	20	)17	2018		2019	2	2020
Code	В		С		D		E	F		G		Н
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

and Lead-free.



## Maximum Ratings – Q1 (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-80	V
Emitter-Base Voltage	V <sub>EBO</sub>	-4.0	V
Continuous Collector Current	I <sub>C(MAX)</sub>	-500	mA
Peak Pulse Collector Current @ DC Increment for $I_C$ ; $I_B = 300$ mA; test duration >10s for each step.	I <sub>CM</sub>	-1.0	А
Base Current	Ι <sub>Β</sub>	-200	mA

## Maximum Ratings – D1, D2 (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	V <sub>RM</sub>	100	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	75	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	53	V
Forward Continuous Current (Note 5)	I <sub>FM</sub>	300	mA
Average Rectified Output Current (Note 5)	lo	200	mA
Non-Repetitive Peak Forward Surge Current @ t = 1.0µs	I <sub>FSM</sub>	20	А

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	600	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{ extsf{ heta}JA}$	208	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-65 to +150	°C

## **Electrical Characteristics – Q1** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic (Note 6)	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-80	_	_	V	$I_{\rm C} = -100 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	-80	_	_	V	$I_{\rm C} = -1.0 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-4	_	_	V	$I_E = -100 \mu A$ , $I_C = 0$
Collector Cutoff Current	I <sub>CBO</sub>	_	_	-100	nA	$V_{CB} = -60V, I_E = 0$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_		-0.25	V	I <sub>C</sub> = -100mA, I <sub>B</sub> = -10mA
DC Current Transfer Ratio	h <sub>FE</sub>	120	280	500	_	$I_{C} = -10 \text{mA}, V_{CE} = -1.0 \text{V}$

# Electrical Characteristics – D1, D2 (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	V <sub>(BR)R</sub>	75	_	V	I <sub>R</sub> = 100μA
			0.715		I <sub>F</sub> = 5.0mA
Forward Voltage	N	_	0.855	V	I <sub>F</sub> = 10mA
r orward voltage	VF	_	1.0		$I_F = 50 \text{mA}$
		_	1.25		I <sub>F</sub> = 150mA
Leakage Current (Note 6)		_	0.1	μA	V <sub>R</sub> = 75V
Leakage Current (Note 6)	I <sub>R</sub>	_	25	nA	V <sub>R</sub> = 20V
Total Capacitance	Ст	_	1.5	pF	V <sub>R</sub> = 0V, f = 1.0MHz
Reverse Recovery Time	t <sub>rr</sub>	_	4	ns	$I_F = I_R = 10 \text{mA},$ $I_{rr} = 0.1 \text{ x } I_R, R_L = 100 \Omega$

Notes: 5. Device mounted on FR-4 PC board with recommended pad layout, which can be found on our website at http://www.diodes.com. 6. Short duration pulse test used to minimize self-heating effect.



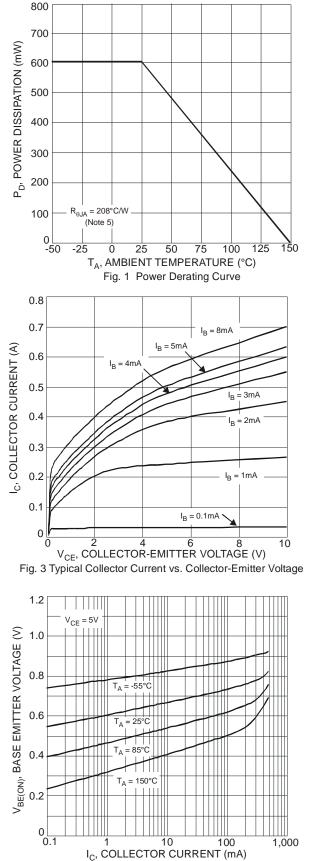
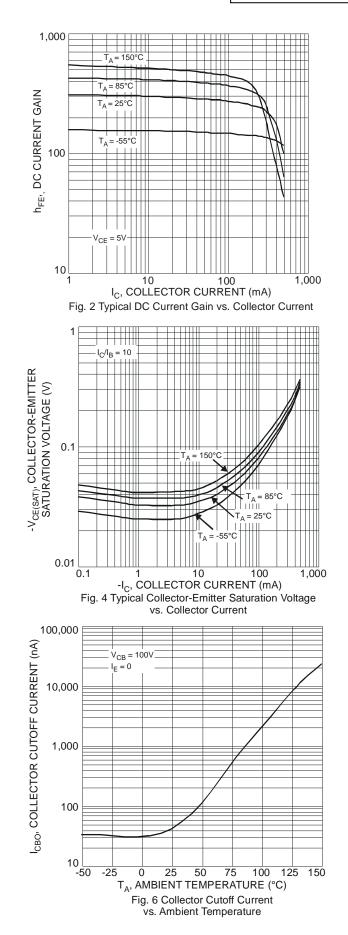
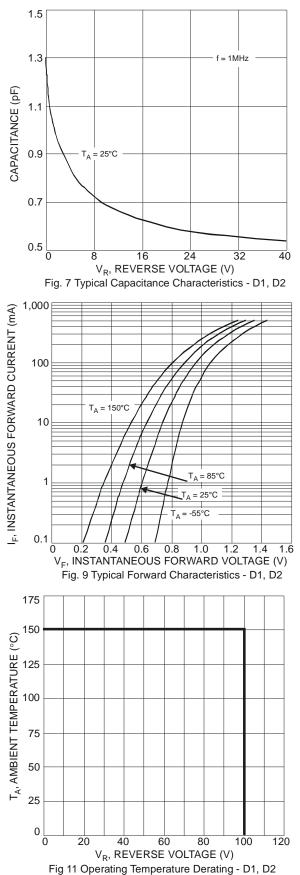


Fig. 5 Typical Base Emitter Voltage vs. Collector Current



## DSM80100M





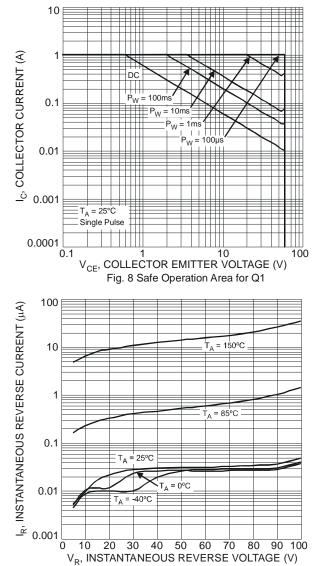
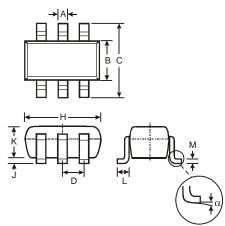


Fig. 10 Typical Reverse Characteristics - D1, D2



# **Package Outline Dimensions**

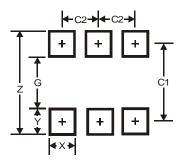
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT26						
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
В	1.50	1.70	1.60			
С	2.70	3.00	2.80			
D	_		0.95			
Н	2.90	3.10	3.00			
J	0.013	0.10	0.05			
Κ	<b>K</b> 1.00 1.30 1.10					
L	L 0.35 0.55 0.40					
М	0.10	0.20	0.15			
α 0° 8° —						
ali d	imensi	ons in	mm			

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95



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